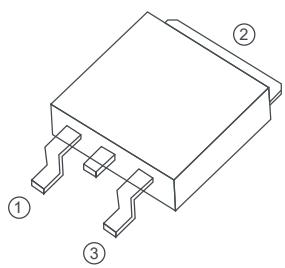


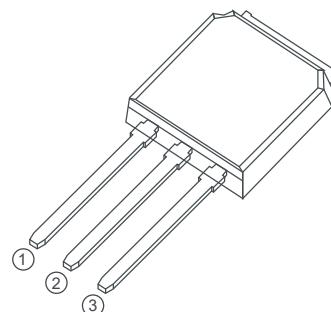
C106 Series
4A SCRs
Sensitive Gate SCRs



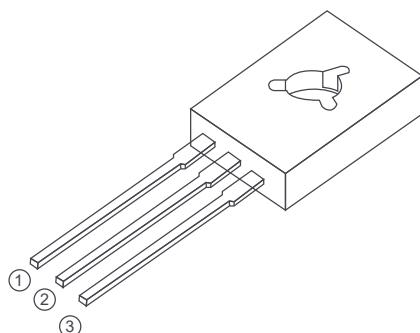
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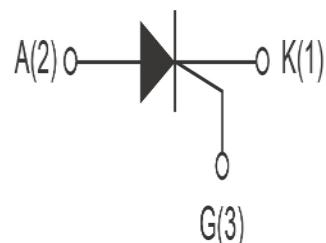
TO-252



TO-251



TO-126



FEATURES

- > IT(RMS):4A
- > VGT: 0.8V
- > VDRM VRRM:600V

APPLICATIONS

Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Absolute Maximum Ratings ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
VDRM VRRM	Repetitive Peak Off-State Voltage		600	V
IT(RMS)	R.M.S On-State Current		4	A
IT(AV)	average On-State Current		2.5	A
ITSM	Surge On-State Current	$F=50\text{Hz}, tp=10\text{ms}$	30	A
I^2t	I^2t for fusing	$tp=10\text{ms}$	4.5	A^2s
IGM	Peak Gate Current	$tp=20\mu\text{s} T_j=110^\circ\text{C}$	0.2	A
PG(AV)	Average Gate Power Dissipation	$T_j=110^\circ\text{C}$	0.2	W
PGM	Peak Gate Power Dissipation	$tp=20\mu\text{s} T_j=110^\circ\text{C}$	1	W
T_j	Operating Junction Temperature		$\sim 40\sim125$	$^\circ\text{C}$
TSTG	Storage Temperature		$\sim 40\sim150$	$^\circ\text{C}$

Electrical Characteristics ($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Value	Unit
IDRM	Repetitive Peak Off-State Current	$T_c=25^\circ\text{C}$	≤ 5	uA
		$T_c=110^\circ\text{C}$	≤ 100	uA
IRRMM	Repetitive Peak Reverse Current	$T_j=25^\circ\text{C}$	≤ 5	uA
		$T_j=110^\circ\text{C}$	≤ 100	uA
VTM	Forward "on" voltage	$IT=8\text{A} tp=380\mu\text{s}$	≤ 1.7	V
VGD	Gate nontrigger voltage	$VD=VDRM, T_j=125^\circ\text{C}$	≥ 0.2	V
IL	Latching current	$IG=1.2IGT$	≤ 6	mA
IH	Holding current	$VD=12\text{V}, IGT=0.1\text{A}$	≤ 5	mA
VGT	Gate trigger voltage	$VD=12\text{V}$	≤ 0.8	V
IGT	Gate trigger current	$VD=12\text{V}, IT=0.1\text{A}$	≤ 120	uA
dv/dt	Critical-rate of rise of commutation voltage	$VD=2/3VDRM, T_j=110^\circ\text{C}, RGK=1\text{k}\Omega$	≥ 10	V/us

FIG1

Maximum power dissipation versus RMS on-state current

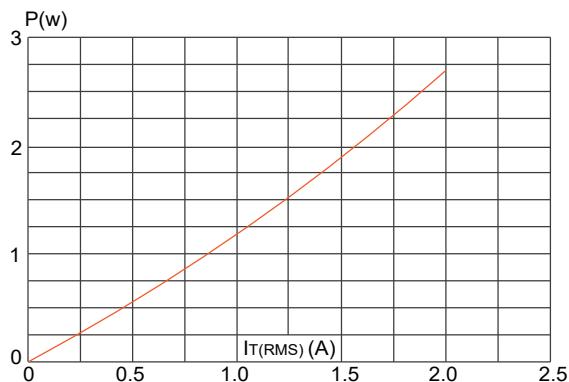


FIG2

RMS on-state current versus case temperature

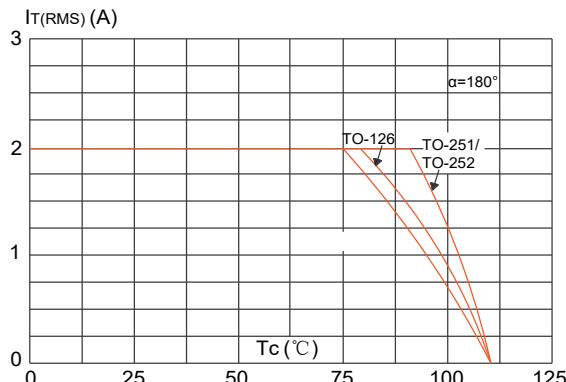


FIG3

Surge peak on-state current versus number of cycles

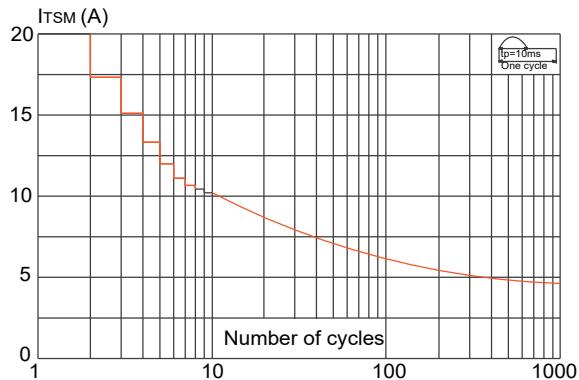


FIG4

On-state characteristics (maximum values)

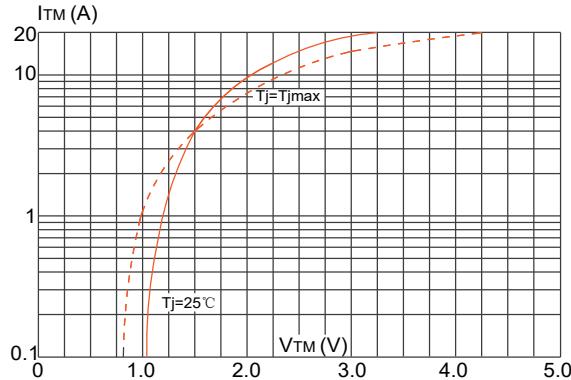


FIG5

Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of I^2t ($dI/dt < 100A/\mu s$)

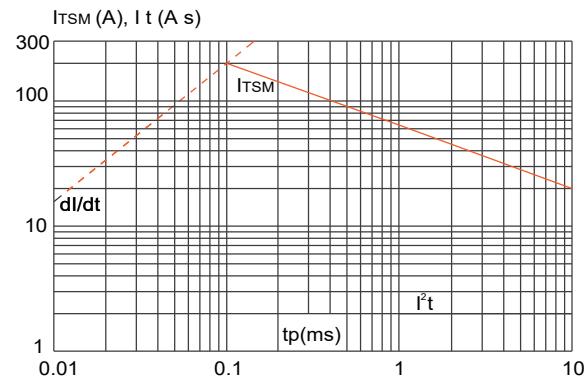
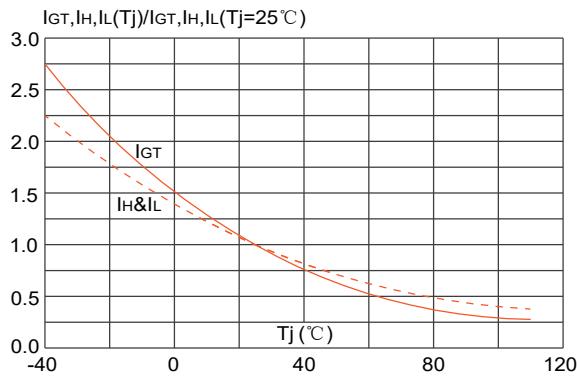
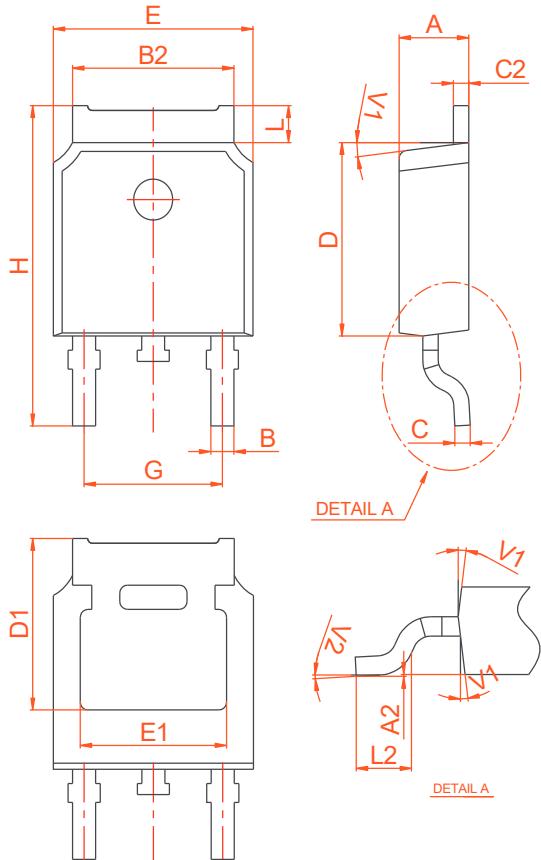


FIG6

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature



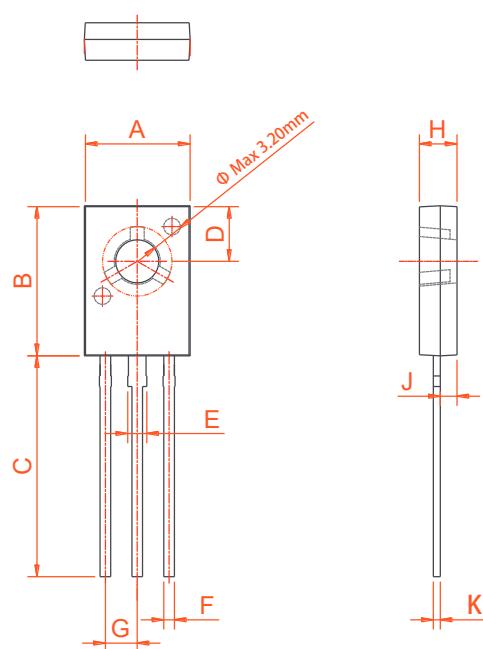
PACKAGE MECHANICAL DATA



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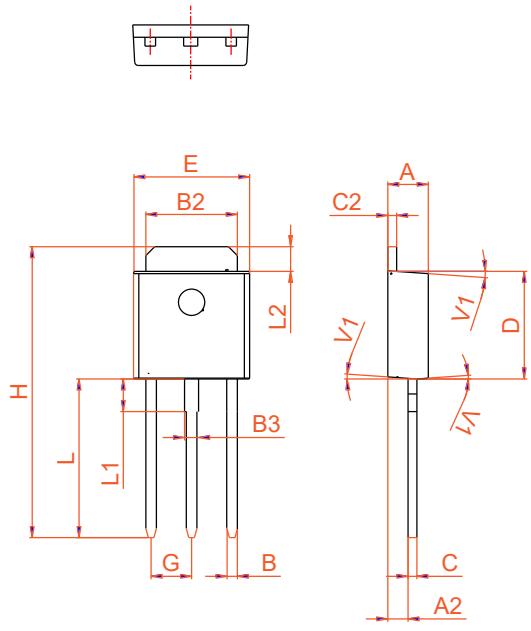
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.03		0.23	0.001		0.009
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
C	0.45		0.55	0.018		0.022
C2	2.70		2.90	0.106		0.114
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G	4.40		4.70	0.173		0.185
H	9.35		10.6	0.368		0.417
L1	1.30		1.70	0.051		0.067
L2	1.37		1.50	0.054		0.059
L3		0.8			0.031	
L4		0.8			0.031	
V1		4°			4°	
V2	0°		8°	0°		8°

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	7.40		7.80	0.291		0.307
B	10.6		11.2	0.417		0.441
C	15.3		16.3	0.602		0.642
D	3.90		4.10	0.154		0.161
E	1.17		1.47	0.046		0.058
F	0.66		0.86	0.026		0.034
G		2.29		0.090		
H	2.50		2.90	0.098		0.114
J	1.10		1.50	0.043		0.059
K	0.45		0.60	0.018		0.024



TO-126

PACKAGE MECHANICAL DATA



TO-251

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20		2.40	0.086		0.095
A2	0.90		1.20	0.035		0.047
B	0.55		0.65	0.022		0.026
B2	5.10		5.40	0.200		0.213
B3	0.76		0.85	0.030		0.033
C	0.45		0.62	0.018		0.024
C2	0.48		0.62	0.019		0.024
D	6.00		6.20	0.236		0.244
E	6.40		6.70	0.252		0.264
G		2.30			0.091	
H	16.0		17.0	0.630		0.669
L	8.90		9.40	0.350		0.370
L1	1.80		1.90	0.071		0.075
L2	1.37		1.50	0.054		0.059
V1		4°			4°	



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